

**0.5 to 6.0 GHz SPDT SWITCH****DESCRIPTION**

The μ PG2415TK is a GaAs MMIC SPDT (Single Pole Double Throw) switch for 0.5 to 6.0 GHz applications, including dual-band wireless LAN.

This device operates with dual control switching voltages of 2.7 to 5.3 V. This device can operate at frequencies from 0.5 to 6.0 GHz, with low insertion loss and high isolation.

This device is housed in a 6-pin lead-less minimold package (1511 PKG) and is suitable for high-density surface mounting.

FEATURES

- Switch control voltage : $V_{\text{cont (H)}} = 3.0 \text{ V TYP.}$
: $V_{\text{cont (L)}} = 0 \text{ V TYP.}$
- Low insertion loss : $L_{\text{ins}} = 0.45 \text{ dB TYP. @ } f = 2.5 \text{ GHz}$
: $L_{\text{ins}} = 0.65 \text{ dB TYP. @ } f = 6.0 \text{ GHz}$
- High isolation : $ISL = 28 \text{ dB TYP. @ } f = 2.5 \text{ GHz}$
: $ISL = 26 \text{ dB TYP. @ } f = 6.0 \text{ GHz}$
- Handling power : $P_{\text{in (0.1 dB)}} = +31.0 \text{ dBm TYP. @ } f = 2.0 \text{ to } 6.0 \text{ GHz}$
- High-density surface mounting : 6-pin lead-less minimold package (1.5 × 1.1 × 0.55 mm)

APPLICATIONS

- Dual-band wireless LAN etc.

ORDERING INFORMATION

Part Number	Order Number	Package	Marking	Supplying Form
μ PG2415TK-E2	μ PG2415TK-E2-A	6-pin lead-less minimold (1511 PKG) (Pb-Free)	G6D	<ul style="list-style-type: none">• Embossed tape 8 mm wide• Pin 1, 6 face the perforation side of the tape• Qty 5 kpcs/reel

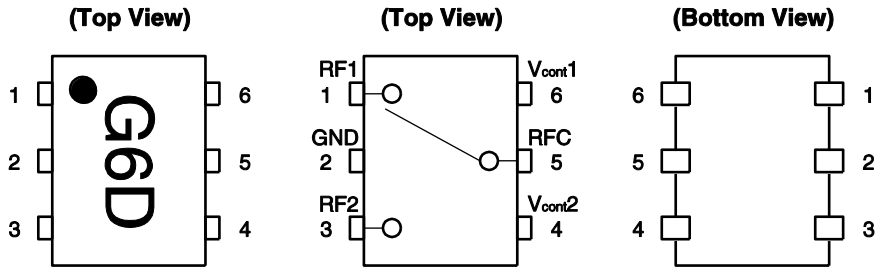
Remark To order evaluation samples, please contact your nearby sales office.

Part number for sample order: μ PG2415TK-A

Caution Although this device is designed to be as robust as possible, ESD (Electrostatic Discharge) can damage this device. This device must be protected at all times from ESD. Static charges may easily produce potentials of several kilovolts on the human body or equipment, which can discharge without detection. Industry-standard ESD precautions must be employed at all times.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



Pin No.	Pin Name
1	RF1
2	GND
3	RF2
4	V _{cont2}
5	RFC
6	V _{cont1}

SW TRUTH TABLE

ON Path	V _{cont1}	V _{cont2}
RFC-RF1	High	Low
RFC-RF2	Low	High

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Switch Control Voltage	V _{cont}	+6.0 ^{Note}	V
Input Power (V _{cont (H)} = 3.0 V)	P _{in}	+34.0	dBm
Input Power (V _{cont (H)} = 5.0 V)	P _{in}	+35.0	dBm
Power Dissipation (average)	P _D	0.15	W
Operating Ambient Temperature	T _A	-45 to +85	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Note |V_{cont1} - V_{cont2}| ≤ 6.0 V

RECOMMENDED OPERATING RANGE (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Operating Frequency	f	0.5	-	6.0	GHz
Switch Control Voltage (H)	V _{cont (H)}	2.7	3.0	5.3	V
Switch Control Voltage (L)	V _{cont (L)}	-0.2	0	0.2	V
Control Voltage Difference	ΔV _{cont (H)} , ΔV _{cont (L)} ^{Note}	-0.1	0	0.1	V

Note ΔV_{cont (H)} = V_{cont1 (H)} - V_{cont2 (H)}
 ΔV_{cont (L)} = V_{cont1 (L)} - V_{cont2 (L)}

ELECTRICAL CHARACTERISTICS

(T_A = +25°C, V_{cont} (H) = 3.0 V, V_{cont} (L) = 0 V, Z_o = 50 Ω, DC blocking capacitors = 8 pF, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Insertion Loss 1	L _{ins1}	f = 0.5 to 2.0 GHz ^{Note 1}	–	0.40	0.65	dB
Insertion Loss 2	L _{ins2}	f = 2.0 to 2.5 GHz	–	0.45	0.70	dB
Insertion Loss 3	L _{ins3}	f = 2.5 to 3.8 GHz	–	0.55	0.80	dB
Insertion Loss 4	L _{ins4}	f = 3.8 to 6.0 GHz	–	0.65	0.90	dB
Isolation 1	ISL1	f = 0.5 to 2.0 GHz ^{Note 1}	25	28	–	dB
Isolation 2	ISL2	f = 2.0 to 2.5 GHz	25	28	–	dB
Isolation 3	ISL3	f = 2.5 to 3.8 GHz	25	28	–	dB
Isolation 4	ISL4	f = 3.8 to 6.0 GHz	22	26	–	dB
Return Loss 1	RL1	f = 0.5 to 2.0 GHz ^{Note 1}	15	20	–	dB
Return Loss 2	RL2	f = 2.0 to 2.5 GHz	15	20	–	dB
Return Loss 3	RL3	f = 2.5 to 6.0 GHz	10	15	–	dB
0.1 dB Loss Compression Input Power ^{Note 2}	P _{in (0.1 dB)}	f = 0.5 to 2.0 GHz ^{Note 1}	–	+32.0	–	dBm
		f = 2.0 to 6.0 GHz	–	+31.0	–	dBm
		f = 0.5 to 6.0 GHz ^{Note 1} , V _{cont (H)} = 5.0 V	–	+35.0	–	dBm
1 dB Loss Compression Input Power ^{Note 3}	P _{in (1 dB)}	f = 0.5 to 2.0 GHz ^{Note 1}	–	+34.0	–	dBm
		f = 2.0 to 6.0 GHz	–	+34.0	–	dBm
Input 3rd Order Intercept Point	IIP ₃	f = 2.5 GHz, P _{in} = +20 dBm	–	+60	–	dBm
2nd Harmonics	2f _o	f = 2.5 GHz, P _{in} = +20 dBm	–	80	–	dBc
3rd Harmonics	3f _o	f = 2.5 GHz, P _{in} = +20 dBm	–	80	–	dBc
Switch Control Current	I _{cont}	No RF input	–	0.1	10	μA
Switch Control Speed	t _{sw}	50% CTL to 90/10% RF	–	50	250	ns

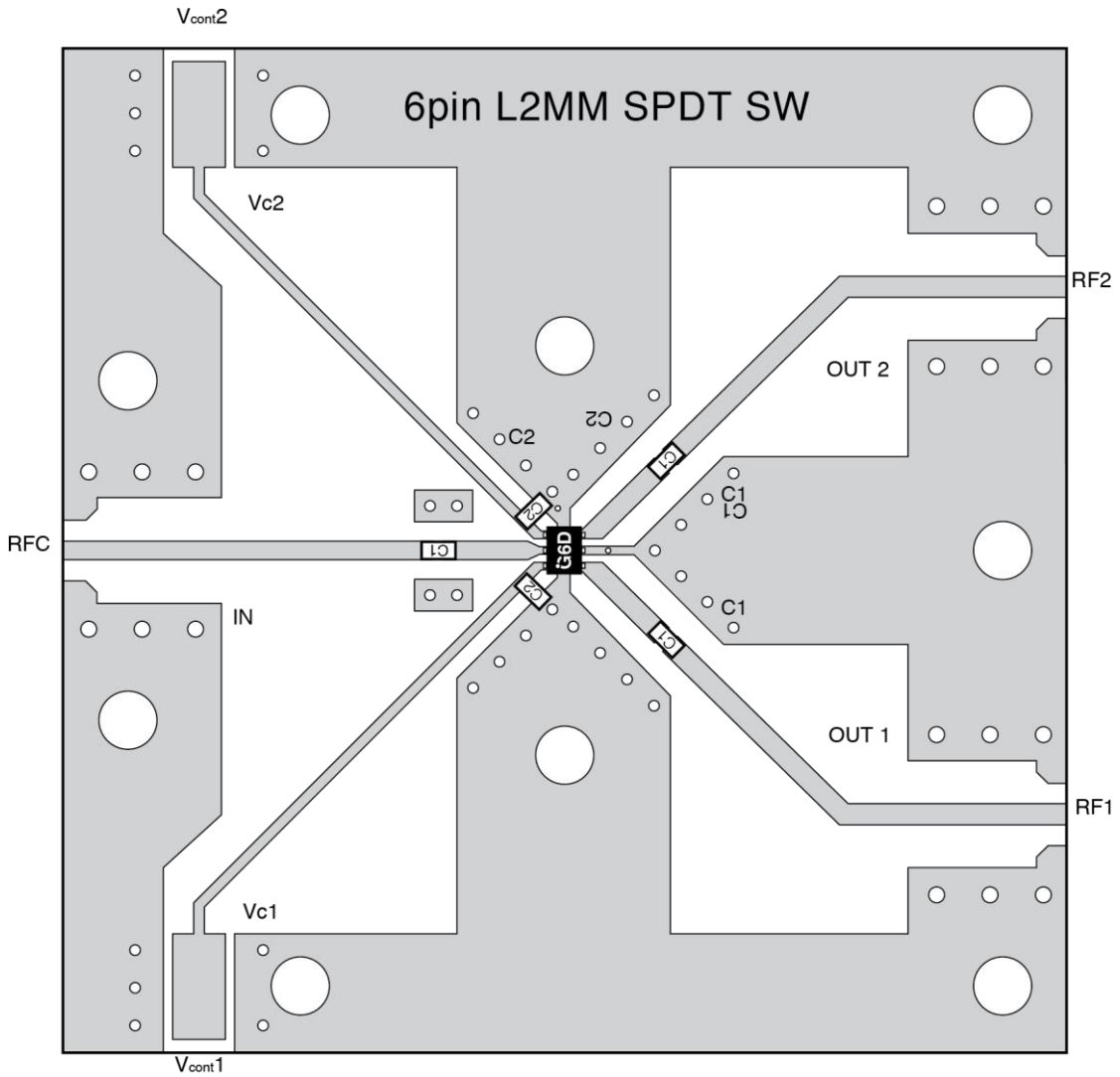
Notes 1. DC blocking capacitors = 56 pF at f = 0.5 to 2.0 GHz

- 2.** P_{in (0.1 dB)} is the measured input power level when the insertion loss increases 0.1 dB more than that of the linear range.
- 3.** P_{in (1 dB)} is the measured input power level when the insertion loss increases 1 dB more than that of the linear range.

Caution It is necessary to use DC blocking capacitors with this device.

The value of DC blocking capacitors should be chosen to accommodate the frequency of operation, bandwidth, switching speed and the condition with actual board of your system.

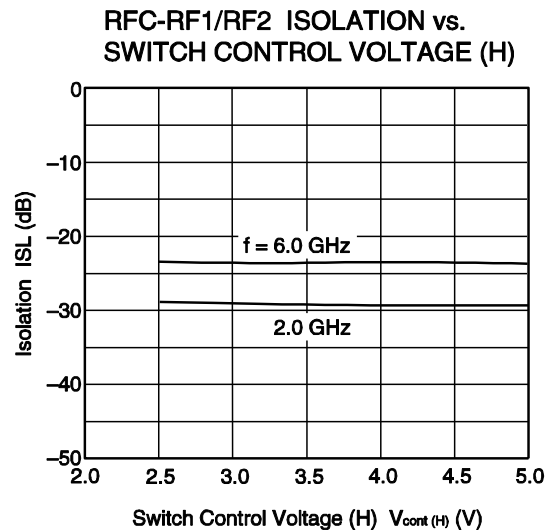
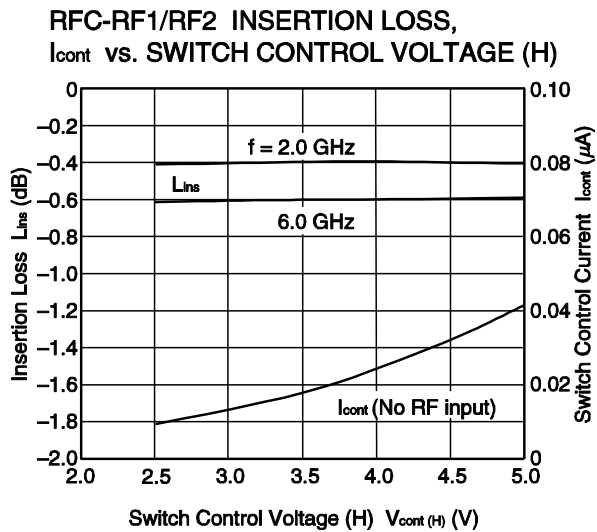
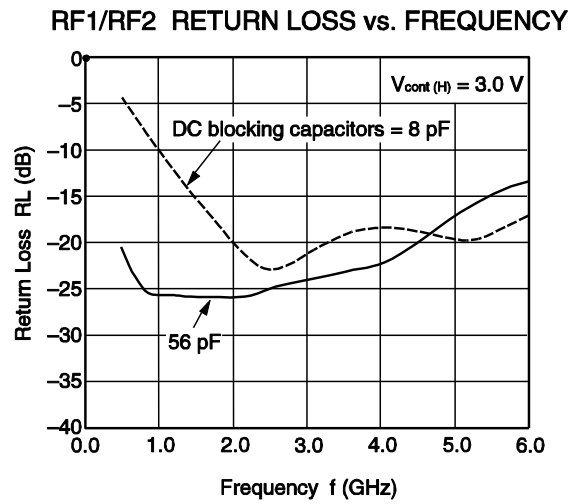
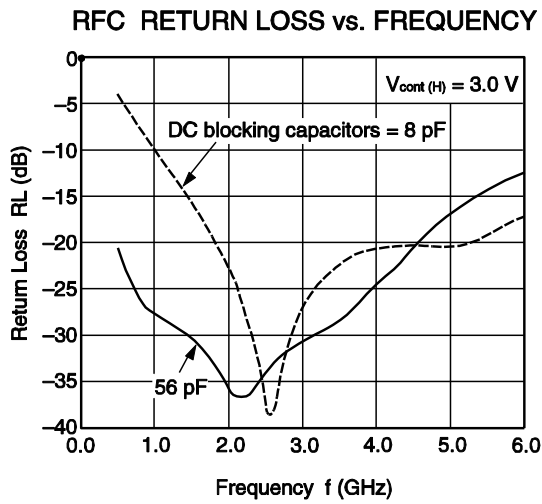
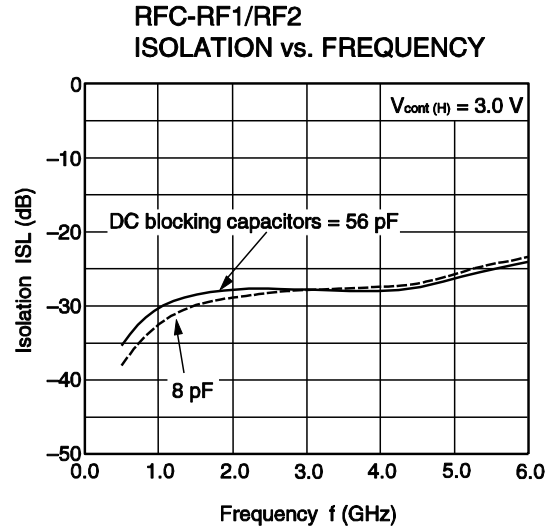
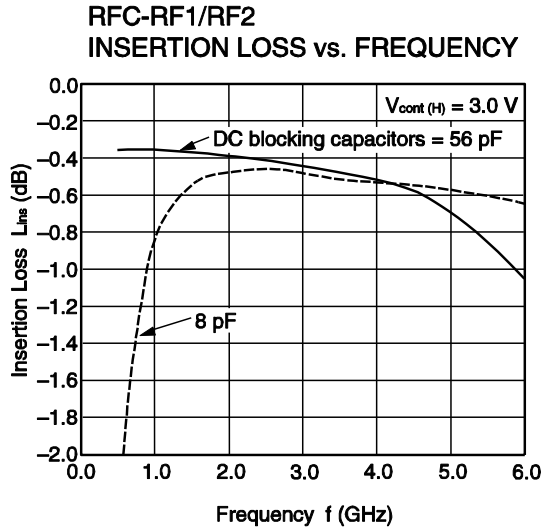
ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD



USING THE EVALUATION BOARD

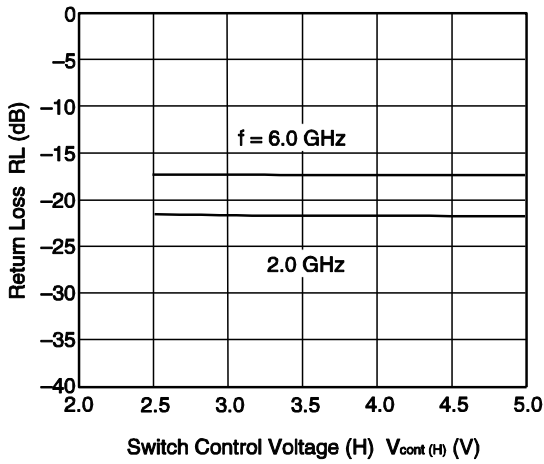
Symbol	Test Conditions	Values
C1	f = 0.5 to 2.0 GHz	56 pF
	f = 2.0 to 6.0 GHz	8 pF
C2		1 000 pF

TYPICAL CHARACTERISTICS ($T_A = +25^\circ\text{C}$, $V_{\text{cont (H)}} = 3.0\text{ V}$, $V_{\text{cont (L)}} = 0\text{ V}$, $Z_O = 50\ \Omega$, DC blocking capacitors = 8 pF, unless otherwise specified)

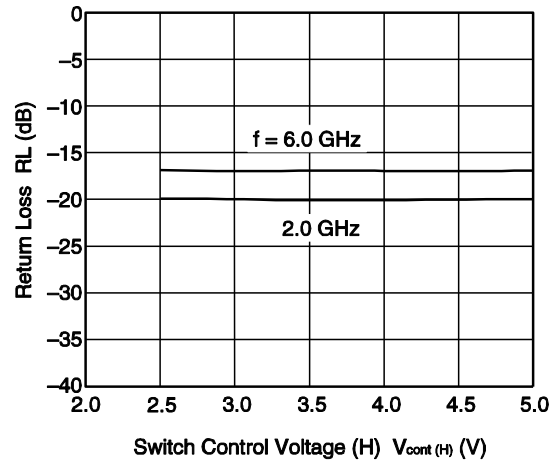


Remark The graphs indicate nominal characteristics.

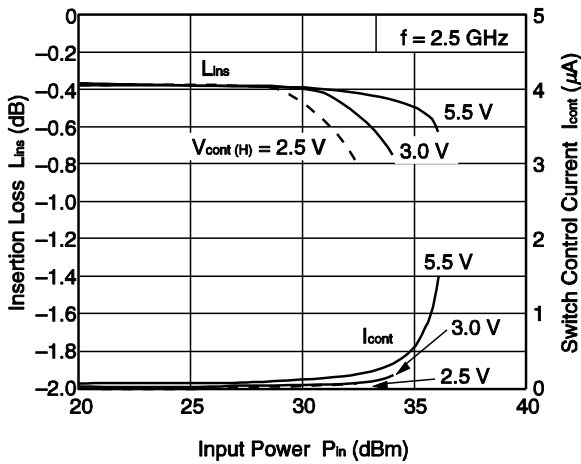
RFC RETURN LOSS vs. SWITCH CONTROL VOLTAGE (H)



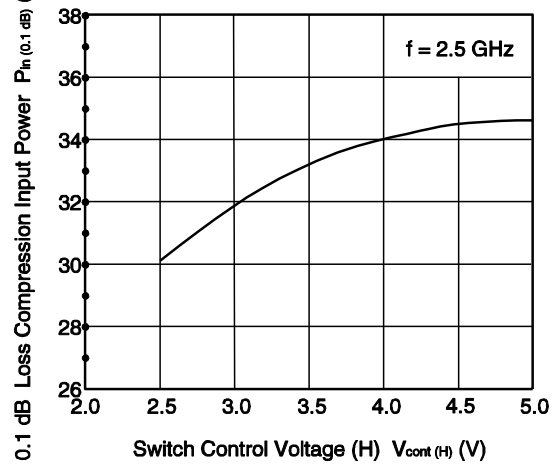
RF1/RF2 RETURN LOSS vs. SWITCH CONTROL VOLTAGE (H)



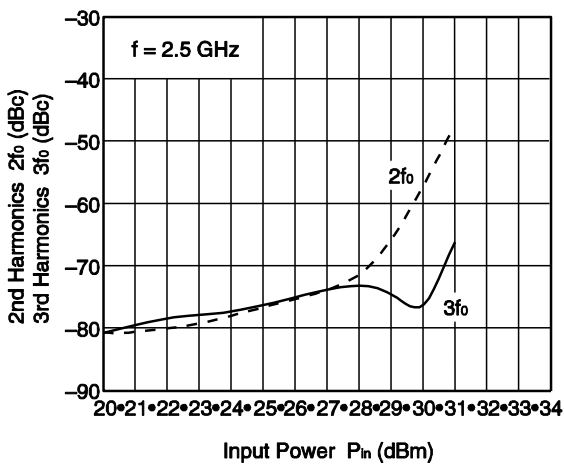
RFC-RF1/RF2 INSERTION LOSS, Icont vs. INPUT POWER



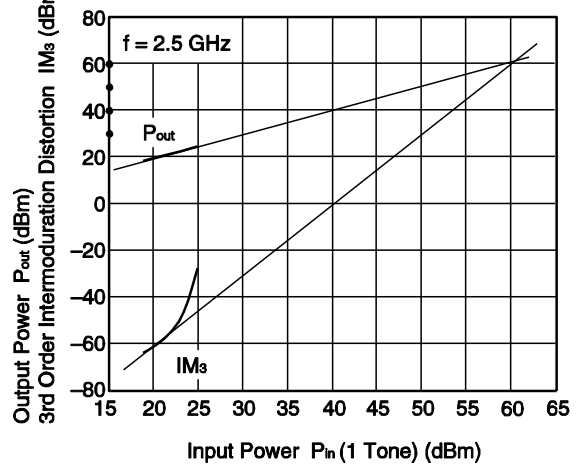
RFC-RF1/RF2 Pin (0.1 dB) vs. SWITCH CONTROL VOLTAGE (H)



RFC-RF1/RF2 • 2fo, 3fo vs. INPUT POWER



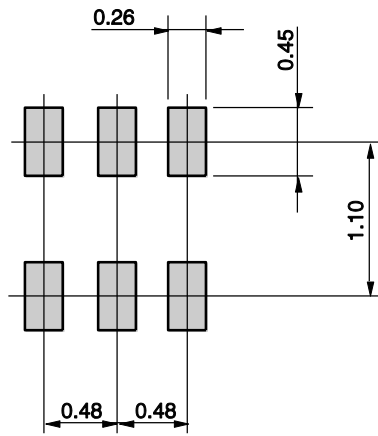
RFC-RF1/RF2 OUTPUT POWER, IM3 vs. INPUT POWER



Remark The graphs indicate nominal characteristics.

MOUNTING PAD LAYOUT DIMENSIONS

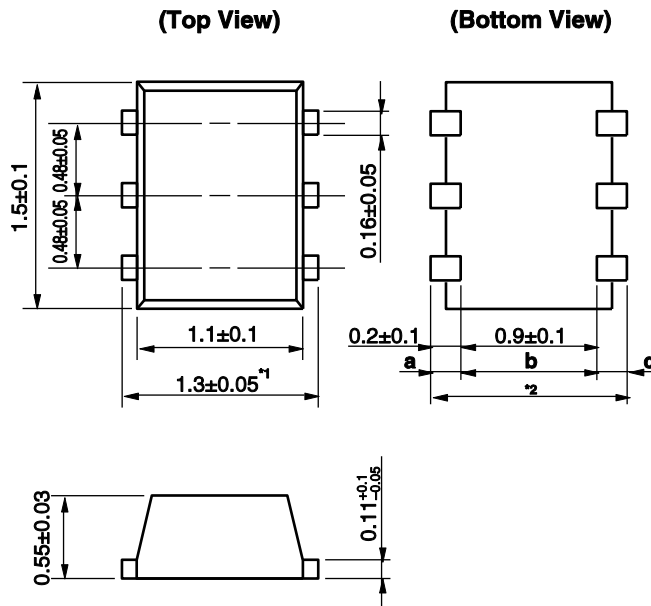
6-PIN LEAD-LESS MINIMOLD (1511 PKG) (UNIT: mm)



Remark The mounting pad layout in this document is for reference only.

PACKAGE DIMENSIONS

6-PIN LEAD-LESS MINIMOLD (1511 PKG) (UNIT: mm)



Remark Dimension ¹ is bigger than dimension ² (dimension ² = a + b + c).

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) : 260°C or below Time at peak temperature : 10 seconds or less Time at temperature of 220°C or higher : 60 seconds or less Preheating time at 120 to 180°C : 120±30 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	IR260
Wave Soldering	Peak temperature (molten solder temperature) : 260°C or below Time at peak temperature : 10 seconds or less Preheating temperature (package surface temperature) : 120°C or below Maximum number of flow processes : 1 time Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	WS260
Partial Heating	Peak temperature (terminal temperature) : 350°C or below Soldering time (per side of device) : 3 seconds or less Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).

<p>Caution</p>	<p>GaAs Products</p>	<p>This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.</p> <ul style="list-style-type: none"> • Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below. <ol style="list-style-type: none"> 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials. 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal. <ul style="list-style-type: none"> • Do not burn, destroy, cut, crush, or chemically dissolve the product. • Do not lick the product or in any way allow it to enter the mouth.
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Вы можете приобрести в компании MosChip.

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<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

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Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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